Docket No.: 51876P352

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re the Application of:

BYUNG-SEOP HONG, ET AL.

Art Group:

Application No.:

Examiner:

Filed:

For: METHOD FOR RELEASING STRESS

DURING SEMICONDUCTOR

DEVICEFABRICATION

INFORMATION DISCLOSURE STATEMENT UNDER 37 C.F.R. §1.97

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the duty of disclosure, enclosed is a copy of Information Disclosure Statement by Applicant (form PTO/SB/08), which is being submitted concurrently with the Utility Application. It is respectfully requested that the cited references be considered and that the enclosed copy of PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s).

-1- 51876P352

The submission of this Information Disclosure Statement is not to be construed as a representation that a search has been made in the subject application and is not to be construed as an admission that the information cited in this statement is material to patentability.

Please charge any fees due to Deposit Account 02-2666. A duplicate copy of the Fee Transmittal (PTO/SB/17) is enclosed for this purpose.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

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Complete if Kn wn Substitute for form 1449A/PTO Application Number INFORMATION DISCLOSURE Filing Date Byung-Seop HONG STATEMENT BY APPLICANT First Named Inventor Art Unit (use as many sheets as necessary) **Examiner Name** 1 1 Sheet of Attorney Docket Number 51876P352

U.S. PATENT DOCUMENTS									
Examiner Initials*	Cite No.1	Document Number Number - Kind Code ² (if known)	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear				
		US-2002/0197837 A1	12-26-2002	Kwak et al.					
		US-6,380,044 B1	04-30-2002	Talwar et al.					
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FOREIGN PATENT DOCUMENTS											
Examiner Initials*	Cite No.1	Foreign Patent Document		Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	Ţ [®]					
		Country Code ³ - Number ⁴ - Kind Code ⁵ (if known)	Publication Date MM-DD-YYYY								
		JP 2001-094105	04-06-2001	Samsung Electronics Co Ltd.	Abstract						
		JP 2002-170954	06-14-2002	Hynix Semiconductor Inc.	Abstract						
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Examiner	Date	٦
Signature	Considered	

^{*}Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶Applicant is to place a check mark here if English language Translation is attached.